

NX3L4684

Dual low-ohmic single-pole double-throw analog switch

Rev. 04 — 24 March 2010

Product data sheet

1. General description

The NX3L4684 provides two low-ohmic single-pole double-throw analog switches, suitable for use as an analog or digital multiplexer/demultiplexer. It has a digital select input (nS) with Schmitt trigger action, two independent inputs/outputs (nY0, nY1) and a common input/output (nZ). Schmitt trigger action at the select input (nS) makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 1.4 V to 4.3 V.

A low input voltage threshold allows pin nS to be driven by lower level logic signals without a significant increase in supply current I_{CC} . This makes it possible for the NX3L4684 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation.

The NX3L4684 allows signals with amplitude up to V_{CC} to be transmitted from nZ to nY0 or nY1; or from nY0 or nY1 to nZ. Its low ON resistance (0.3 Ω for Y0 port, 0.5 Ω for Y1 port) and flatness (0.1 Ω) ensures minimal attenuation and distortion of transmitted signals.

2. Features

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak) for Y0 port:
 - ◆ 0.8 Ω (typical) at $V_{CC} = 1.4$ V
 - ◆ 0.5 Ω (typical) at $V_{CC} = 1.65$ V
 - ◆ 0.3 Ω (typical) at $V_{CC} = 2.3$ V
 - ◆ 0.25 Ω (typical) at $V_{CC} = 2.7$ V
 - ◆ 0.25 Ω (typical) at $V_{CC} = 4.3$ V
- Break-before-make switching
- High noise immunity
- ESD protection:
 - ◆ HBM JESD22-A114F Class 3A exceeds 4000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM AEC-Q100-011 revision B exceeds 1000 V
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78B Class II Level A
- 1.8 V control logic at $V_{CC} = 3.6$ V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V_{CC}
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to $+85$ °C and from -40 °C to $+125$ °C

3. Applications

- Cell phone
- PDA
- Portable media player

4. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
NX3L4684GM	−40 °C to +125 °C	XQFN10U	plastic extremely thin quad flat package; no leads; 10 terminals; UTLP based; body 2 × 1.55 × 0.5 mm	SOT1049-2
NX3L4684TK	−40 °C to +125 °C	HVSON10	plastic thermal enhanced very thin small outline package; no leads; 10 terminals; 3 × 3 × 0.85 mm	SOT650-1

5. Marking

Table 2. Marking

Type number	Marking code
NX3L4684GM	D84
NX3L4684TK	D84

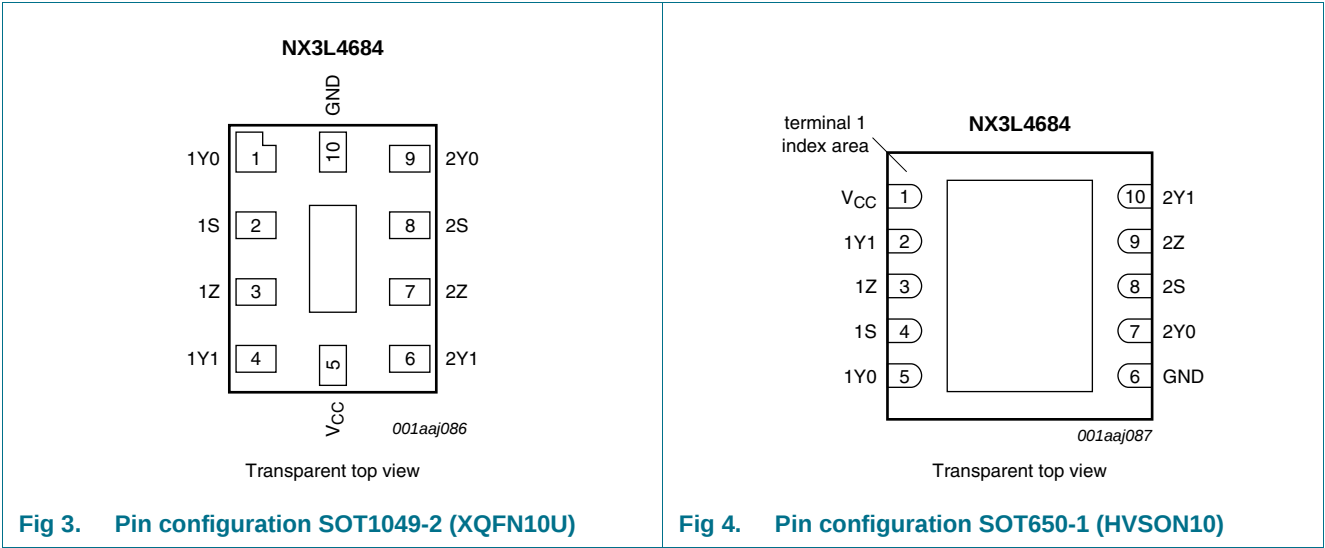
6. Functional diagram

Fig 1. Logic symbol

Fig 2. Logic diagram (one switch)

7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3. Pin description

Symbol	Pin		Description
	SOT1049-2	SOT650-1	
1Y0	1	5	independent input or output
1S	2	4	select input
1Z	3	3	common output or input
1Y1	4	2	independent input or output
V _{CC}	5	1	supply voltage
2Y1	6	10	independent input or output
2Z	7	9	common output or input
2S	8	8	select input
2Y0	9	7	independent input or output
GND	10	6	ground (0 V)

8. Functional description

Table 4. Function table^[1]

Input nS	Channel on
L	nY0
H	nY1

- [1] H = HIGH voltage level;
L = LOW voltage level.

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
V_I	input voltage	select input nS	^[1] -0.5	+4.6	V
V_{SW}	switch voltage	switch input nY0 or nY1	^[2] -0.5	$V_{CC} + 0.5$	V
I_{IK}	input clamping current	$V_I < -0.5$ V	-50	-	mA
I_{SK}	switch clamping current	$V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V	-	±50	mA
I_{SW}	switch current	$V_{SW} > -0.5$ V or $V_{SW} < V_{CC} + 0.5$ V; source or sink current	-	±350	mA
		$V_{SW} > -0.5$ V or $V_{SW} < V_{CC} + 0.5$ V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40$ °C to +125 °C	^[3] -	250	mW

- [1] The minimum input voltage rating may be exceeded if the input current rating is observed.
 [2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.
 [3] For XQFN10U packages: above 132 °C the value of P_{tot} derates linearly with 14.1 mW/K.
 For HVSON10 packages: above 135 °C the value of P_{tot} derates linearly with 17.2 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		1.4	4.3	V
V_I	input voltage	select input nS	0	4.3	V
V_{SW}	switch voltage	switch input nY0 or nY1	^[1] 0	V_{CC}	V
T_{amb}	ambient temperature		-40	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.4$ V to 4.3 V	^[2] -	200	ns/V

- [1] To avoid sinking GND current from terminal nZ when switch current flows in terminal nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no GND current will flow from terminal nYn. In this case, there is no limit for the voltage drop across the switch.
 [2] Applies to select input nS signal levels.

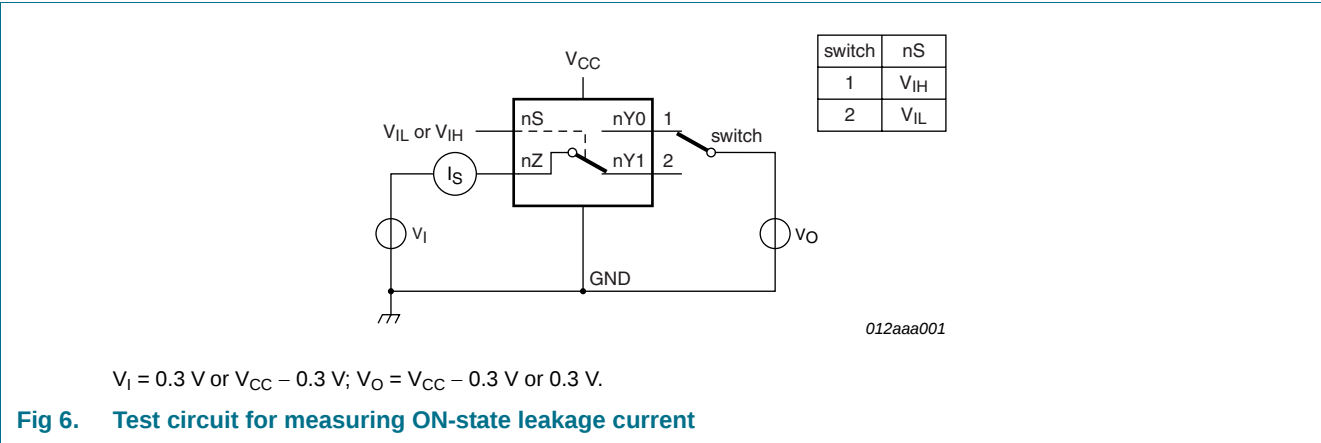
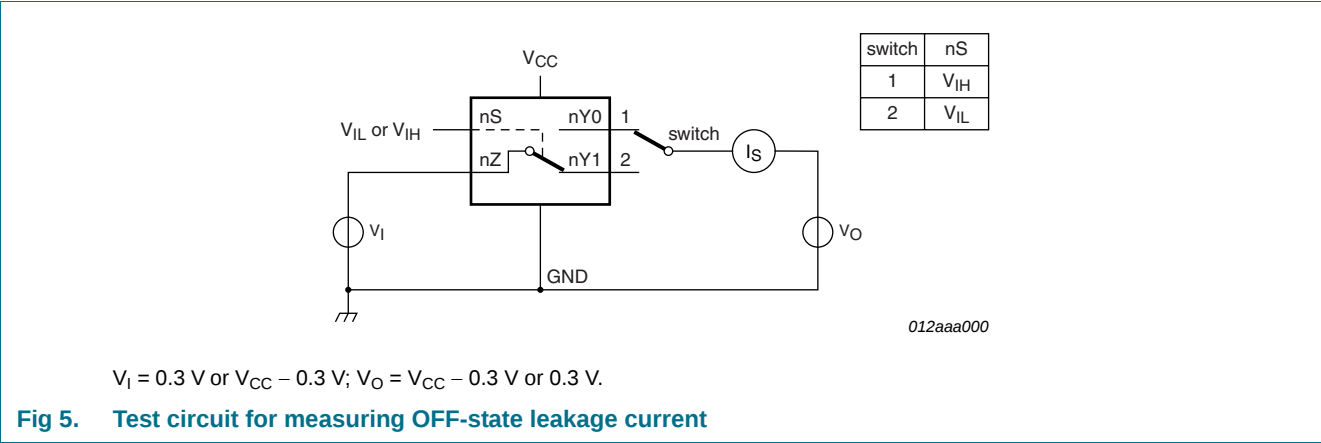
11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	T _{amb} = 25 °C			T _{amb} = –40 °C to +125 °C			Unit
			Min	Typ	Max	Min	Max (85 °C)	Max (125 °C)	
V _{IH}	HIGH-level input voltage	V _{CC} = 1.4 V to 1.6 V	0.9	-	-	0.9	-	-	V
		V _{CC} = 1.65 V to 1.95 V	0.9	-	-	0.9	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V
		V _{CC} = 2.7 V to 3.6 V	1.3	-	-	1.3	-	-	V
		V _{CC} = 3.6 V to 4.3 V	1.4	-	-	1.4	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 1.4 V to 1.6 V	-	-	0.3	-	0.3	0.3	V
		V _{CC} = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.5	-	0.5	0.4	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.5	-	0.5	0.5	V
		V _{CC} = 3.6 V to 4.3 V	-	-	0.6	-	0.6	0.6	V
I _I	input leakage current	select input nS; V _I = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μA
I _{S(OFF)}	OFF-state leakage current	nYn port; see Figure 5							
		V _{CC} = 1.4 V to 3.6 V	-	-	±5	-	±10	±100	nA
		V _{CC} = 3.6 V to 4.3 V	-	-	±10	-	±50	±200	nA
I _{S(ON)}	ON-state leakage current	nZ port; see Figure 6							
		V _{CC} = 1.4 V to 3.6 V	-	-	±5	-	±20	±200	nA
		V _{CC} = 3.6 V to 4.3 V	-	-	±10	-	±50	±400	nA
I _{CC}	supply current	V _I = V _{CC} or GND; V _{SW} = GND or V _{CC}							
		V _{CC} = 3.6 V	-	-	100	-	300	3000	nA
		V _{CC} = 4.3 V	-	-	150	-	500	5000	nA
ΔI _{CC}	additional supply current	V _{SW} = GND or V _{CC}							
		V _I = 2.6 V; V _{CC} = 4.3 V	-	2.0	4.0	-	7	7	μA
		V _I = 2.6 V; V _{CC} = 3.6 V	-	0.35	0.7	-	1	1	μA
		V _I = 1.8 V; V _{CC} = 4.3 V	-	7.0	10.0	-	15	15	μA
		V _I = 1.8 V; V _{CC} = 3.6 V	-	2.5	4.0	-	5	5	μA
		V _I = 1.8 V; V _{CC} = 2.5 V	-	50	200	-	300	500	nA
C _I	input capacitance		-	1.0	-	-	-	-	pF
C _{S(OFF)}	OFF-state capacitance	port nY0	-	65	-	-	-	-	pF
		port nY1	-	35	-	-	-	-	pF
C _{S(ON)}	ON-state capacitance	port nY0	-	260	-	-	-	-	pF
		port nY1	-	160	-	-	-	-	pF

11.1 Test circuits



11.2 ON resistance

Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see [Figure 9](#) to [Figure 21](#).

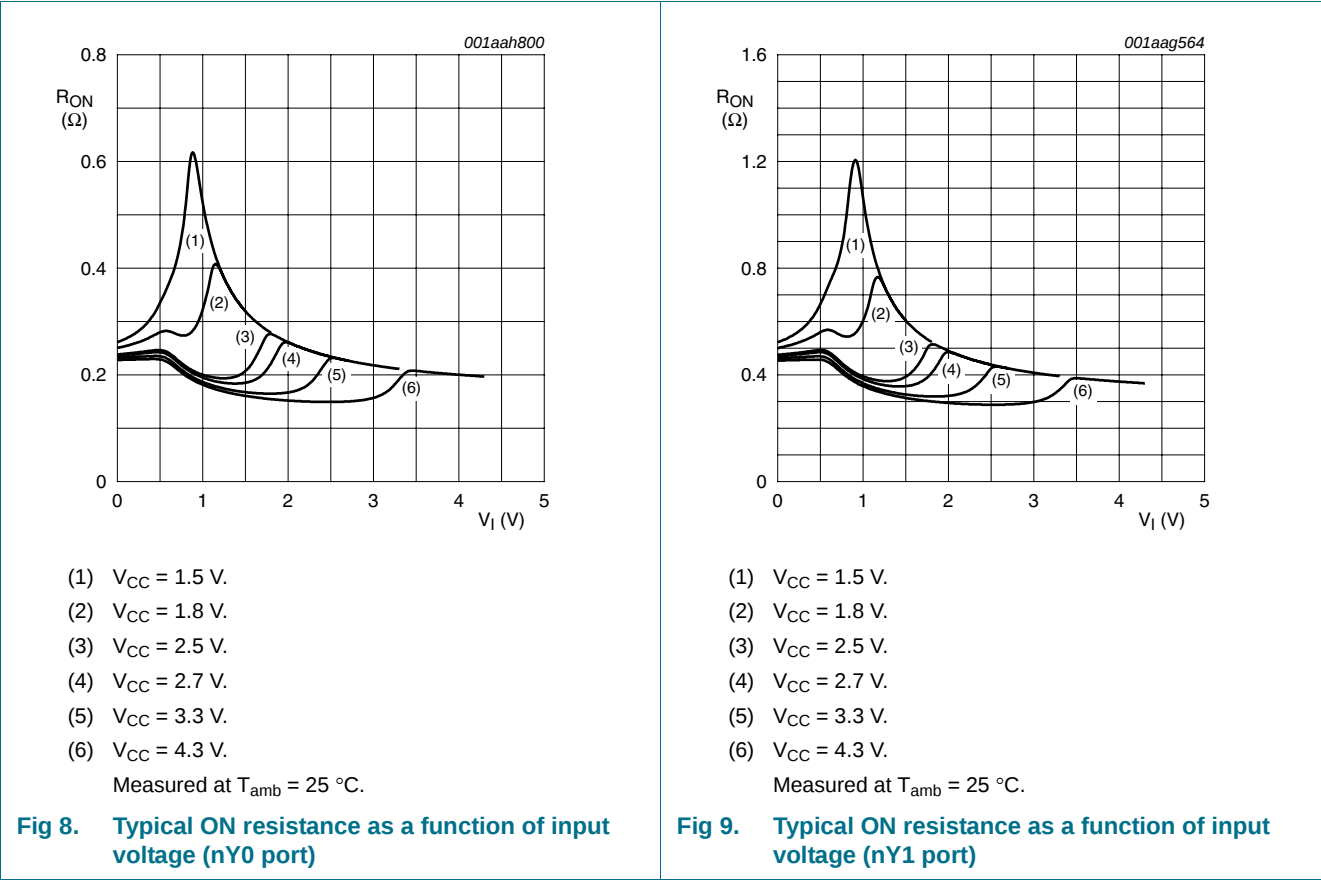
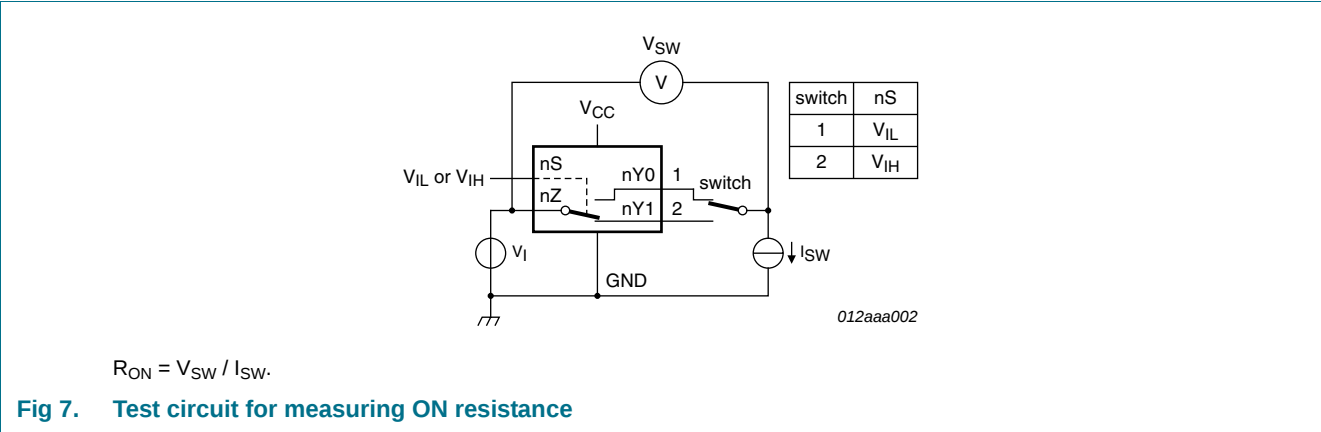
Symbol	Parameter	Conditions	–40 °C to +85 °C			–40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
R _{ON(peak)}	ON resistance (peak)	port nY0; see Figure 7 ; V _I = GND to V _{CC} ; I _{SW} = 100 mA						
		V _{CC} = 1.4 V	-	0.85	2.0	-	2.2	Ω
		V _{CC} = 1.65 V	-	0.55	0.8	-	0.9	Ω
		V _{CC} = 2.3 V	-	0.35	0.5	-	0.6	Ω
		V _{CC} = 2.7 V	-	0.30	0.45	-	0.5	Ω
		V _{CC} = 4.3 V	-	0.30	0.45	-	0.5	Ω
		port nY1; see Figure 7 ; V _I = GND to V _{CC} ; I _{SW} = 100 mA						
		V _{CC} = 1.4 V	-	1.65	3.7	-	4.1	Ω
		V _{CC} = 1.65 V	-	0.95	1.6	-	1.7	Ω
		V _{CC} = 2.3 V	-	0.55	0.8	-	0.9	Ω
		V _{CC} = 2.7 V	-	0.50	0.75	-	0.9	Ω
		V _{CC} = 4.3 V	-	0.50	0.75	-	0.9	Ω
ΔR _{ON}	ON resistance mismatch between channels	V _I = GND to V _{CC} ; I _{SW} = 100 mA [2]						
		V _{CC} = 1.4 V	-	0.15	0.3	-	0.3	Ω
		V _{CC} = 1.65 V	-	0.15	0.2	-	0.3	Ω
		V _{CC} = 2.3 V	-	0.04	0.08	-	0.1	Ω
		V _{CC} = 2.7 V	-	0.04	0.075	-	0.1	Ω
		V _{CC} = 4.3 V	-	0.04	0.075	-	0.1	Ω
R _{ON(flat)}	ON resistance (flatness)	port nY0; V _I = GND to V _{CC} ; I _{SW} = 100 mA [3]						
		V _{CC} = 1.4 V	-	0.5	1.7	-	1.8	Ω
		V _{CC} = 1.65 V	-	0.25	0.6	-	0.7	Ω
		V _{CC} = 2.3 V	-	0.1	0.2	-	0.2	Ω
		V _{CC} = 2.7 V	-	0.1	0.15	-	0.2	Ω
		V _{CC} = 4.3 V	-	0.1	0.20	-	0.25	Ω
		port nY1; V _I = GND to V _{CC} ; I _{SW} = 100 mA [3]						
		V _{CC} = 1.4 V	-	1.0	3.3	-	3.6	Ω
		V _{CC} = 1.65 V	-	0.5	1.2	-	1.3	Ω
		V _{CC} = 2.3 V	-	0.15	0.3	-	0.35	Ω
		V _{CC} = 2.7 V	-	0.13	0.3	-	0.35	Ω
		V _{CC} = 4.3 V	-	0.2	0.4	-	0.45	Ω

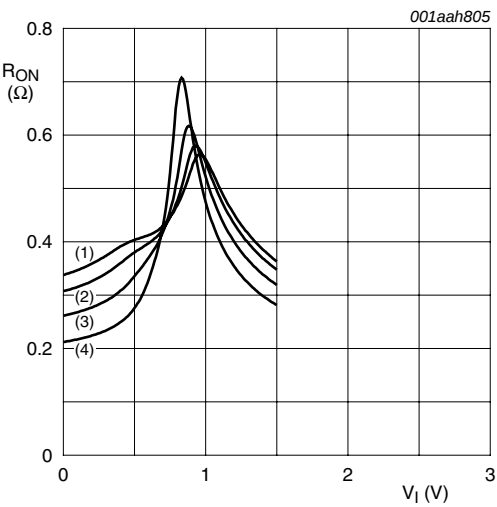
[1] Typical values are measured at T_{amb} = 25 °C.

[2] Measured at identical V_{CC}, temperature and input voltage.

[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

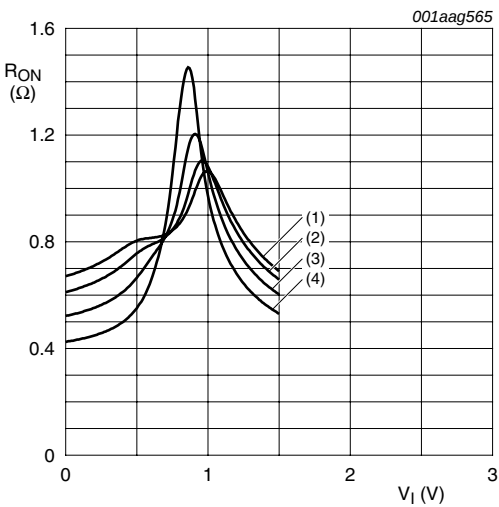
11.3 ON resistance test circuit and graphs





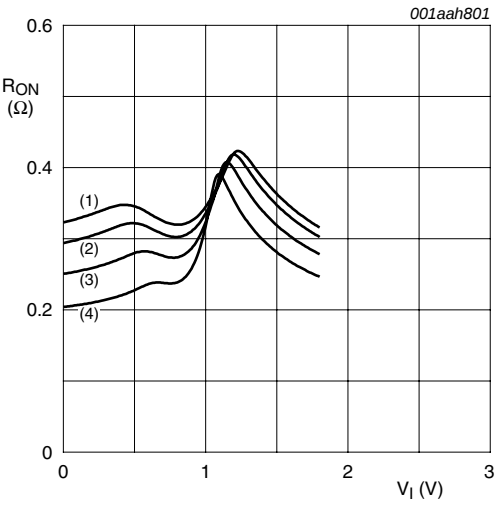
- (1) $T_{amb} = 125$ °C.
- (2) $T_{amb} = 85$ °C.
- (3) $T_{amb} = 25$ °C.
- (4) $T_{amb} = -40$ °C.

Fig 10. ON resistance as a function of input voltage;
 $V_{CC} = 1.5$ V (nY0 port)



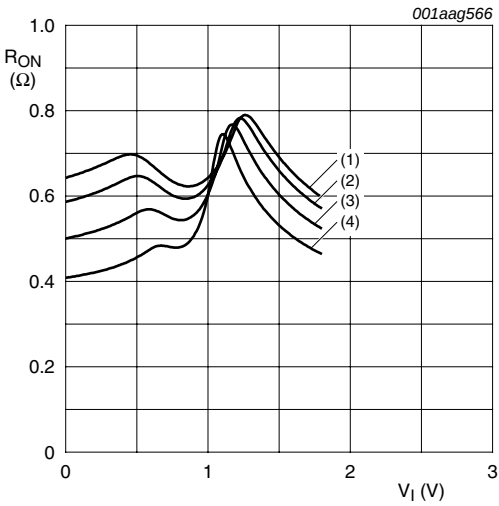
- (1) $T_{amb} = 125$ °C.
- (2) $T_{amb} = 85$ °C.
- (3) $T_{amb} = 25$ °C.
- (4) $T_{amb} = -40$ °C.

Fig 11. ON resistance as a function of input voltage;
 $V_{CC} = 1.5$ V (nY1 port)



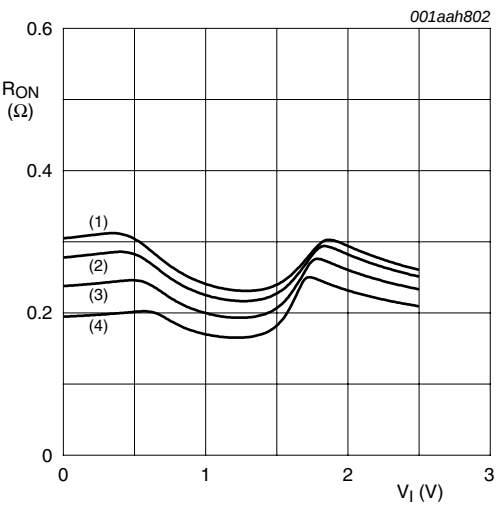
- (1) $T_{amb} = 125$ °C.
- (2) $T_{amb} = 85$ °C.
- (3) $T_{amb} = 25$ °C.
- (4) $T_{amb} = -40$ °C.

Fig 12. ON resistance as a function of input voltage;
 $V_{CC} = 1.8$ V (nY0 port)



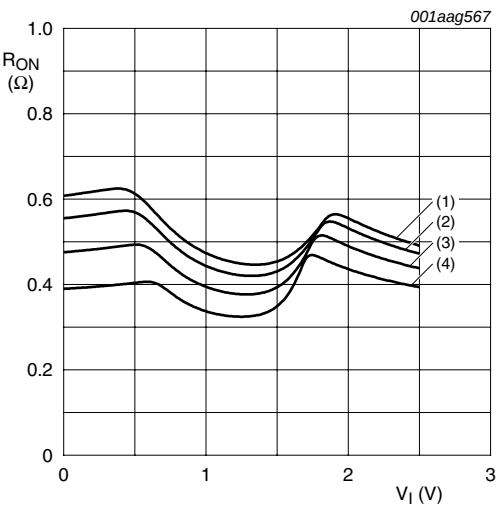
- (1) $T_{amb} = 125$ °C.
- (2) $T_{amb} = 85$ °C.
- (3) $T_{amb} = 25$ °C.
- (4) $T_{amb} = -40$ °C.

Fig 13. ON resistance as a function of input voltage;
 $V_{CC} = 1.8$ V (nY1 port)



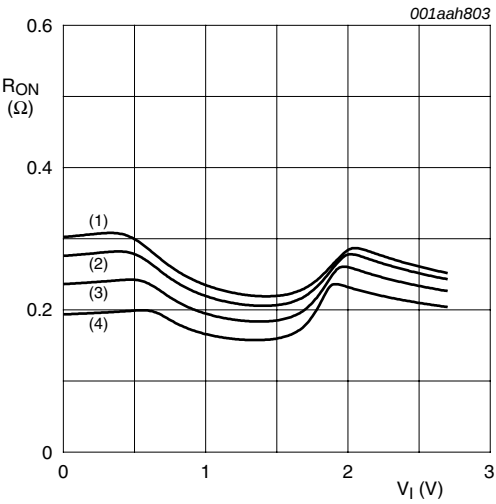
- (1) $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2) $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3) $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4) $T_{amb} = -40\text{ }^{\circ}\text{C}.$

Fig 14. ON resistance as a function of input voltage;
 $V_{CC} = 2.5$ V (nY0 port)



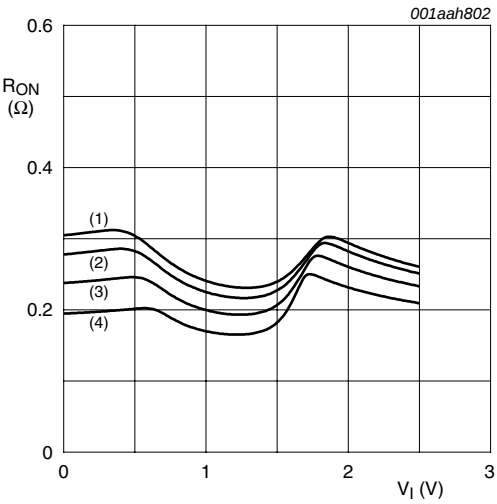
- (1) $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2) $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3) $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4) $T_{amb} = -40\text{ }^{\circ}\text{C}.$

Fig 15. ON resistance as a function of input voltage;
 $V_{CC} = 2.5$ V (nY1 port)



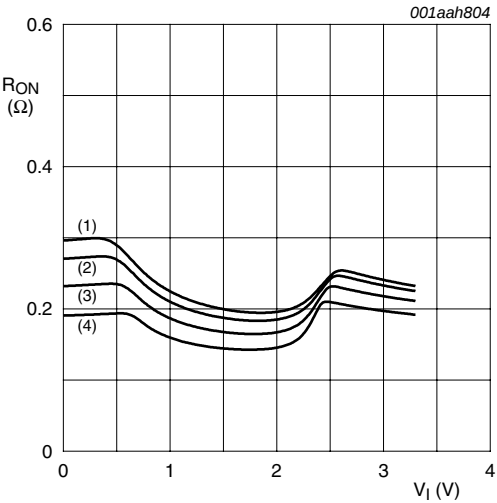
- (1) $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2) $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3) $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4) $T_{amb} = -40\text{ }^{\circ}\text{C}.$

Fig 16. ON resistance as a function of input voltage;
 $V_{CC} = 2.7$ V (nY0 port)



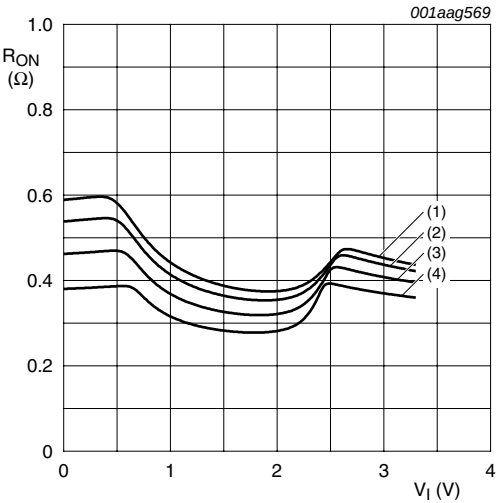
- (1) $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2) $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3) $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4) $T_{amb} = -40\text{ }^{\circ}\text{C}.$

Fig 17. ON resistance as a function of input voltage;
 $V_{CC} = 2.7$ V (nY1 port)



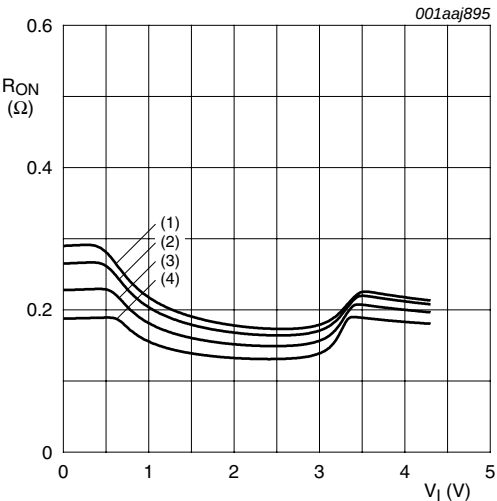
- (1) $T_{amb} = 125$ °C.
- (2) $T_{amb} = 85$ °C.
- (3) $T_{amb} = 25$ °C.
- (4) $T_{amb} = -40$ °C.

Fig 18. ON resistance as a function of input voltage;
 $V_{CC} = 3.3$ V (nY0 port)



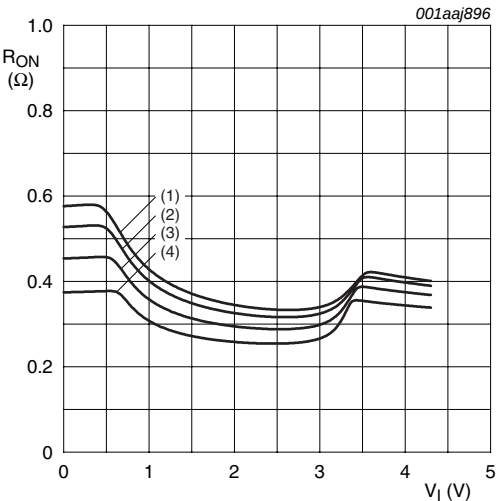
- (1) $T_{amb} = 125$ °C.
- (2) $T_{amb} = 85$ °C.
- (3) $T_{amb} = 25$ °C.
- (4) $T_{amb} = -40$ °C.

Fig 19. ON resistance as a function of input voltage;
 $V_{CC} = 3.3$ V (nY1 port)



- (1) $T_{amb} = 125$ °C.
- (2) $T_{amb} = 85$ °C.
- (3) $T_{amb} = 25$ °C.
- (4) $T_{amb} = -40$ °C.

Fig 20. ON resistance as a function of input voltage;
 $V_{CC} = 4.3$ V (nY0 port)



- (1) $T_{amb} = 125$ °C.
- (2) $T_{amb} = 85$ °C.
- (3) $T_{amb} = 25$ °C.
- (4) $T_{amb} = -40$ °C.

Fig 21. ON resistance as a function of input voltage;
 $V_{CC} = 4.3$ V (nY1 port)

12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see [Figure 24](#).

Symbol	Parameter	Conditions	T _{amb} = 25 °C			T _{amb} = -40 °C to +125 °C			Unit
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)	
t _{en}	enable time	nS to nZ or nYn; see Figure 22							
		V _{CC} = 1.4 V to 1.6 V	-	50	100	-	130	130	ns
		V _{CC} = 1.65 V to 1.95 V	-	35	80	-	85	95	ns
		V _{CC} = 2.3 V to 2.7 V	-	24	50	-	55	60	ns
		V _{CC} = 2.7 V to 3.6 V	-	20	45	-	50	55	ns
		V _{CC} = 3.6 V to 4.3 V	-	20	45	-	50	55	ns
t _{dis}	disable time	nS to nZ or nYn; see Figure 22							
		V _{CC} = 1.4 V to 1.6 V	-	30	70	-	80	90	ns
		V _{CC} = 1.65 V to 1.95 V	-	18	55	-	60	65	ns
		V _{CC} = 2.3 V to 2.7 V	-	11	25	-	30	35	ns
		V _{CC} = 2.7 V to 3.6 V	-	9	20	-	25	30	ns
		V _{CC} = 3.6 V to 4.3 V	-	9	20	-	25	30	ns
t _{b-m}	break-before-make time	see Figure 23 ^[2]							
		V _{CC} = 1.4 V to 1.6 V	-	20	-	9	-	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	19	-	7	-	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	13	-	4	-	-	ns
		V _{CC} = 2.7 V to 3.6 V	-	10	-	2	-	-	ns
		V _{CC} = 3.6 V to 4.3 V	-	10	-	1	-	-	ns

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

12.1 Waveform and test circuits

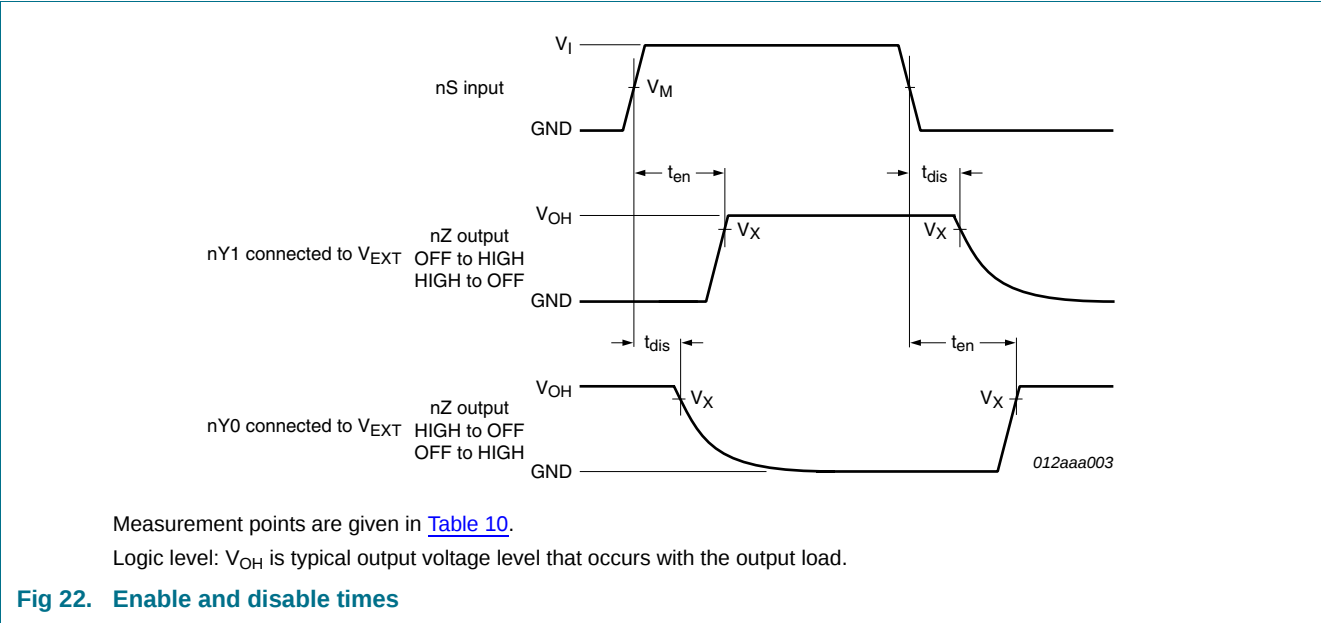


Table 10. Measurement points

Supply voltage	Input	Output
V_{CC}	V_M	V_X
1.4 V to 4.3 V	$0.5V_{CC}$	$0.9V_{OH}$

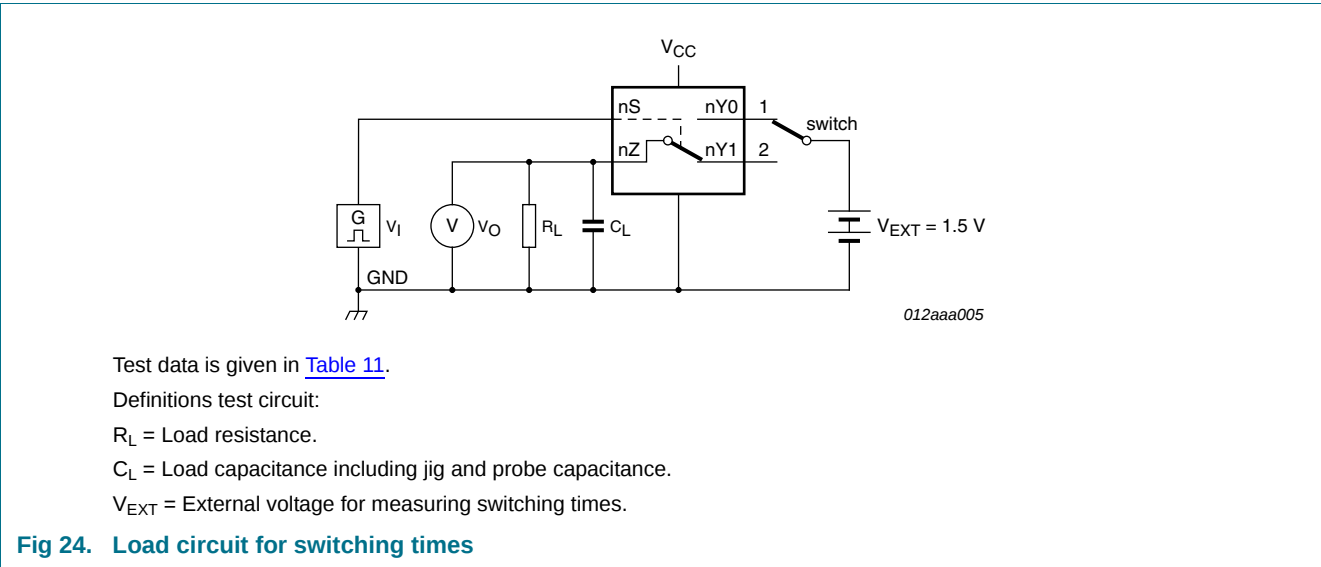
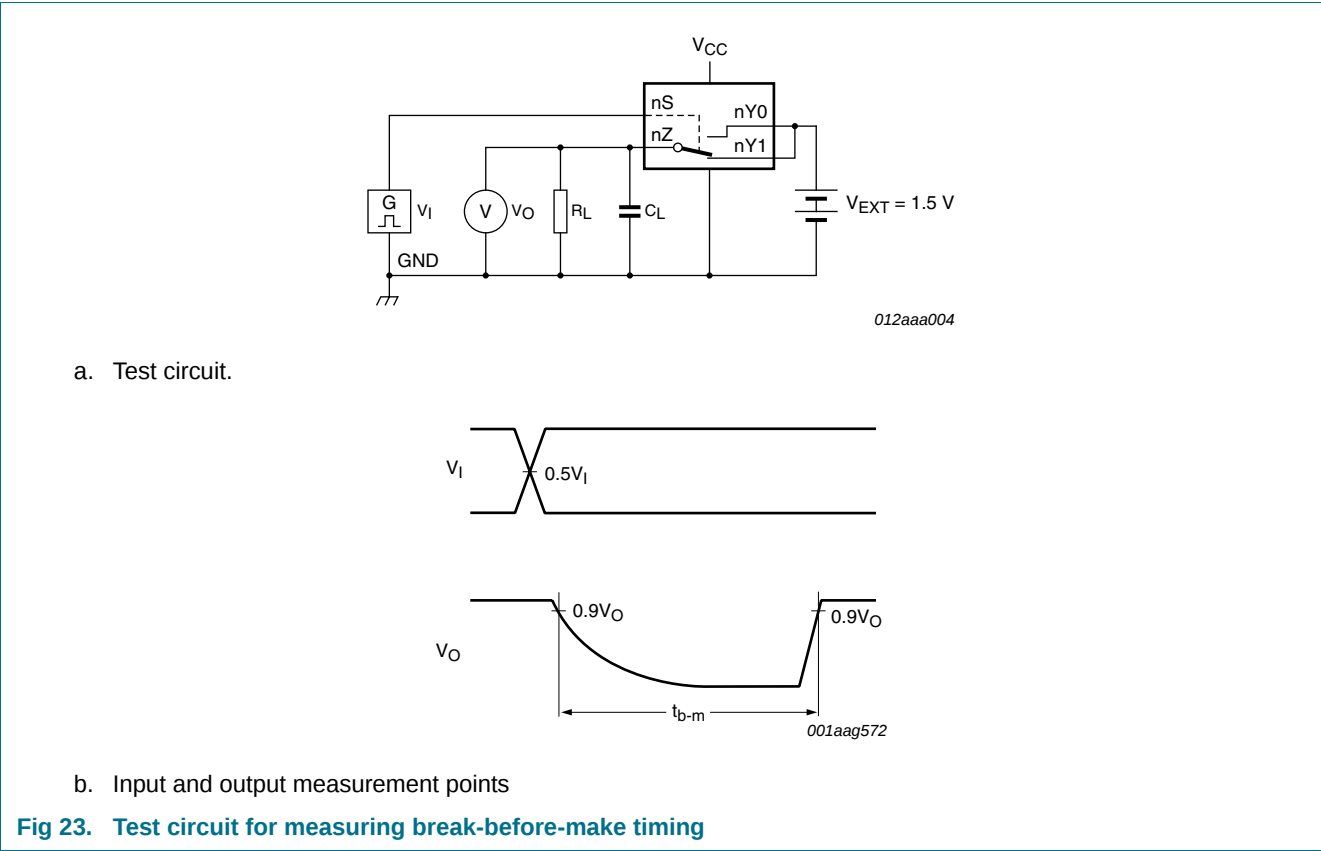


Table 11. Test data

Supply voltage	Input		Load	
V_{CC}	V_I	t_r, t_f	C_L	R_L
1.4 V to 4.3 V	V_{CC}	≤ 2.5 ns	35 pF	50 Ω

12.2 Additional dynamic characteristics

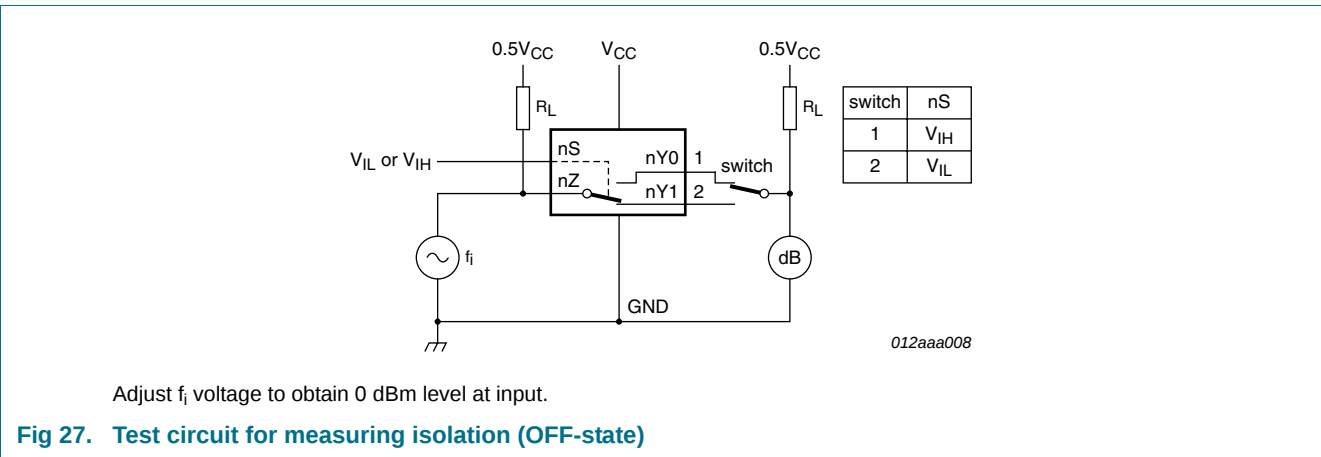
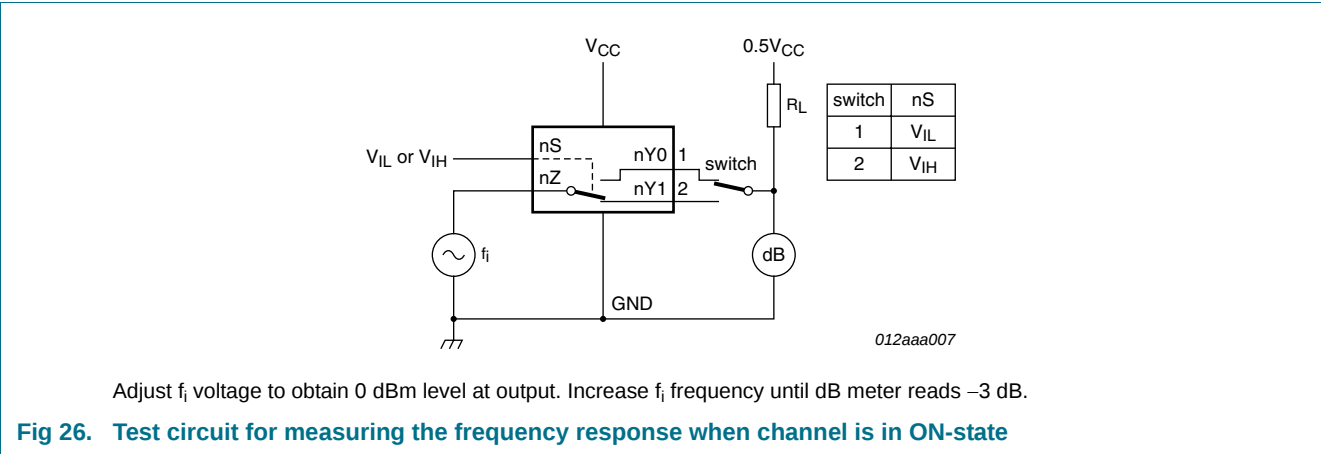
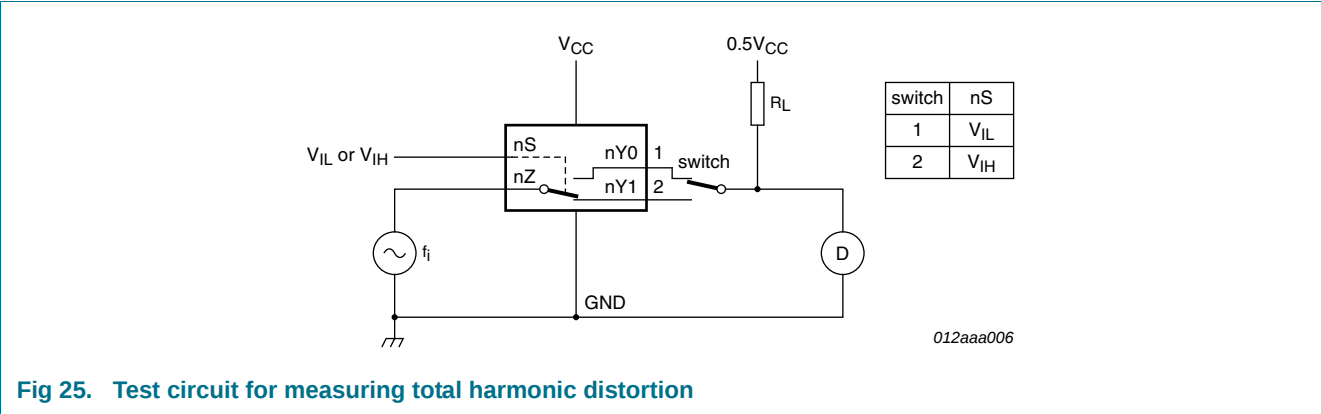
Table 12. Additional dynamic characteristics

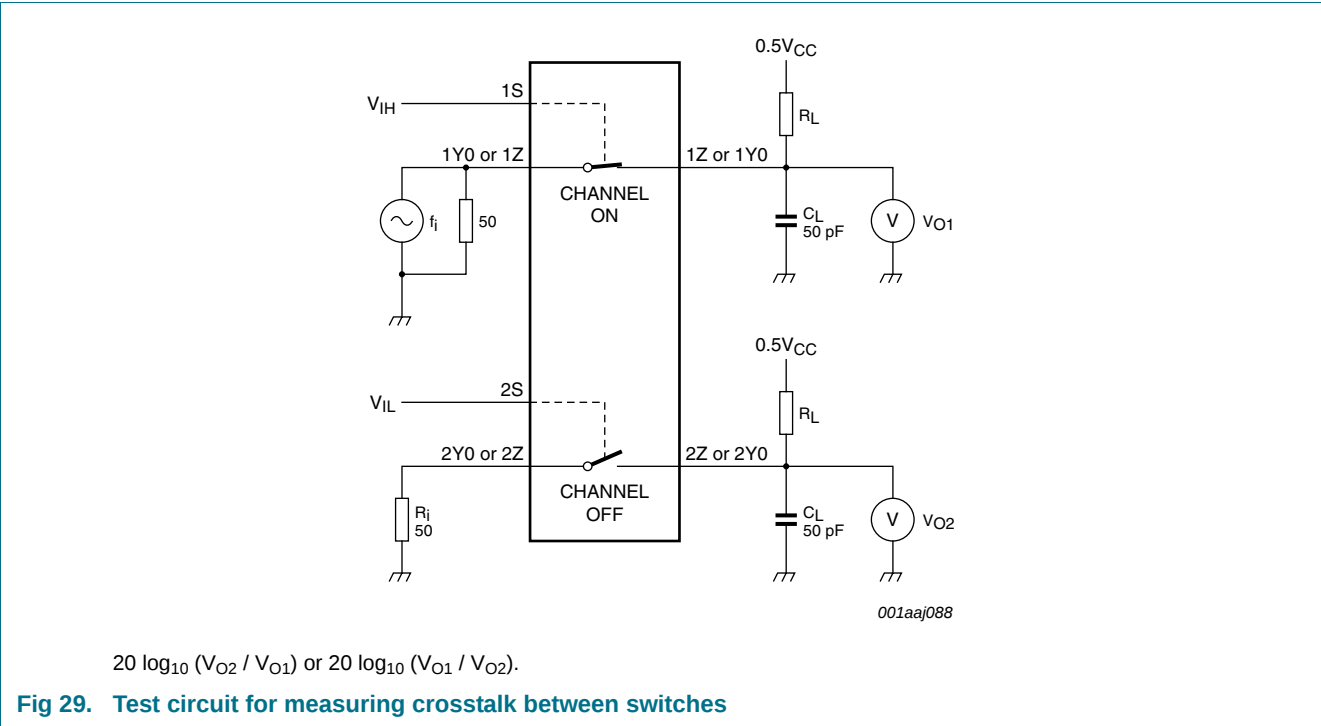
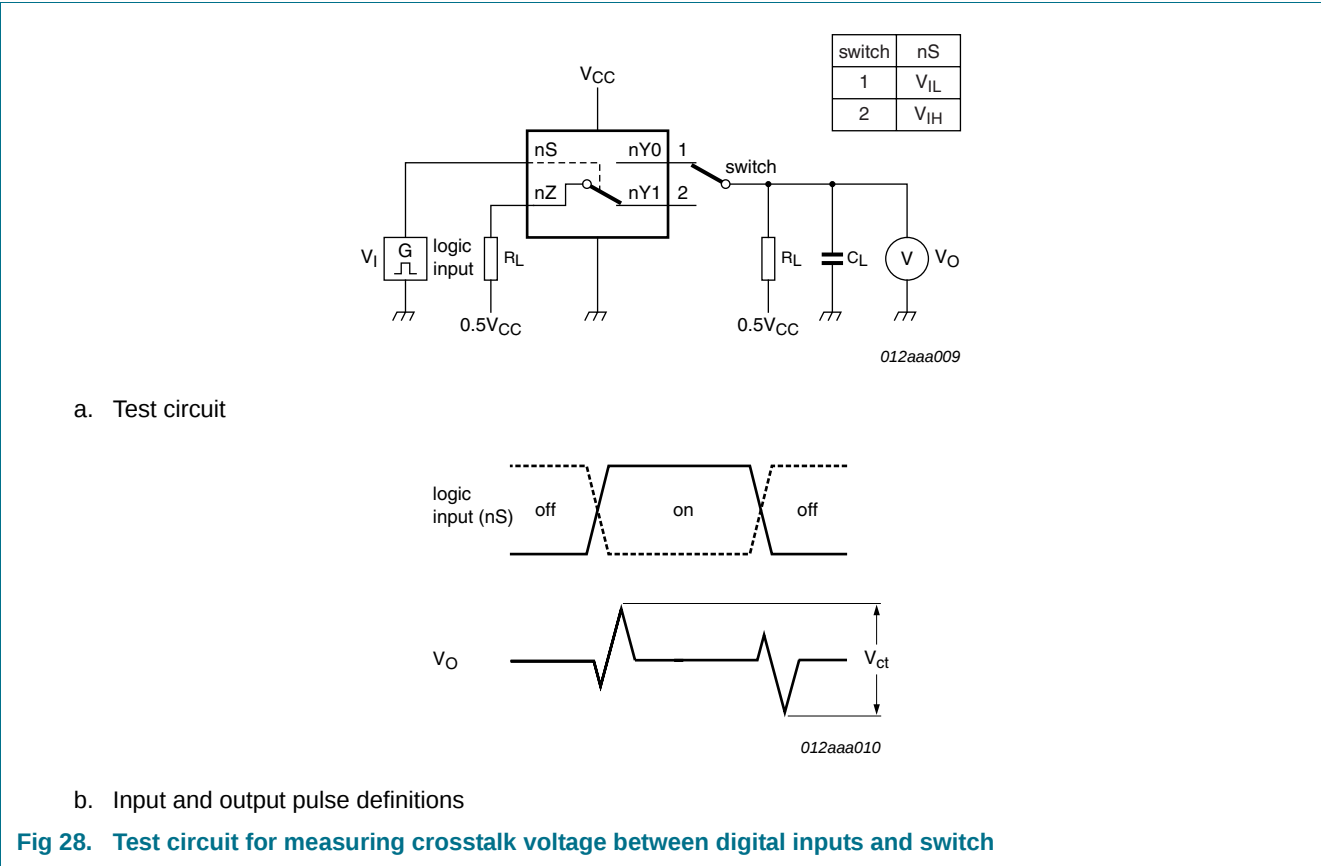
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); V_I = GND or V_{CC} (unless otherwise specified); $t_r = t_f \leq 2.5$ ns.

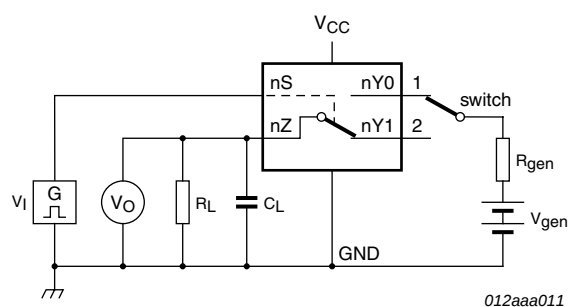
Symbol	Parameter	Conditions	T _{amb} = 25 °C			Unit
			Min	Typ	Max	
THD	total harmonic distortion	$f_i = 20$ Hz to 20 kHz; $R_L = 32 \Omega$; see Figure 25 ^[1]				
		$V_{CC} = 1.4$ V; $V_I = 1$ V (p-p)	-	0.06	-	%
		$V_{CC} = 1.65$ V; $V_I = 1.2$ V (p-p)	-	0.02	-	%
		$V_{CC} = 2.3$ V; $V_I = 1.5$ V (p-p)	-	0.02	-	%
		$V_{CC} = 2.7$ V; $V_I = 2$ V (p-p)	-	0.02	-	%
		$V_{CC} = 4.3$ V; $V_I = 2$ V (p-p)	-	0.02	-	%
		$V_{CC} = 3.0$ V; $V_I = 1$ V (p-p); $R_L = 600 \Omega$	-	0.01	-	%
$f_{(-3dB)}$	-3 dB frequency response	$R_L = 50 \Omega$; see Figure 26 ^[1]				
		port nY0; $V_{CC} = 1.4$ V to 4.3 V	-	15	-	MHz
		port nY1; $V_{CC} = 1.4$ V to 4.3 V	-	20	-	MHz
α_{iso}	isolation (OFF-state)	$f_i = 100$ kHz; $R_L = 50 \Omega$; see Figure 27 ^[1]				
		$V_{CC} = 1.4$ V to 4.3 V	-	-90	-	dB
V_{ct}	crosstalk voltage	between digital inputs and switch; $f_i = 1$ MHz; $C_L = 50$ pF; $R_L = 50 \Omega$; see Figure 28				
		$V_{CC} = 1.4$ V to 3.6 V	-	0.5	-	V
		$V_{CC} = 3.6$ V to 4.3 V	-	0.7	-	V
Xtalk	crosstalk	between switches; ^[1] $f_i = 100$ kHz; $R_L = 50 \Omega$; see Figure 29				
		$V_{CC} = 1.4$ V to 4.3 V	-	-90	-	dB
Q_{inj}	charge injection	$f_i = 1$ MHz; $C_L = 0.1$ nF; $R_L = 1$ M Ω ; $V_{gen} = 0$ V; $R_{gen} = 0 \Omega$; see Figure 30				
		$V_{CC} = 1.5$ V	-	10	-	pC
		$V_{CC} = 1.8$ V	-	14	-	pC
		$V_{CC} = 2.5$ V	-	21	-	pC
		$V_{CC} = 3.3$ V	-	30	-	pC
		$V_{CC} = 4.3$ V	-	50	-	pC

[1] f_i is biased at $0.5V_{CC}$.

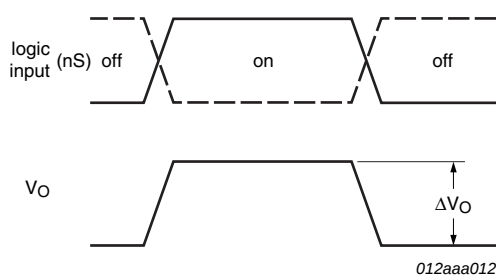
12.3 Test circuits







a. Test circuit.



b. Input and output pulse definitions

Definition: $Q_{inj} = \Delta V_O \times C_L$.

ΔV_O = output voltage variation.

R_{gen} = generator resistance.

V_{gen} = generator voltage.

Fig 30. Test circuit for measuring charge injection

13. Package outline

XQFN10U: plastic extremely thin quad flat package; no leads; 10 terminals;
UTLP based; body 2 x 1.55 x 0.5 mm

SOT1049-2

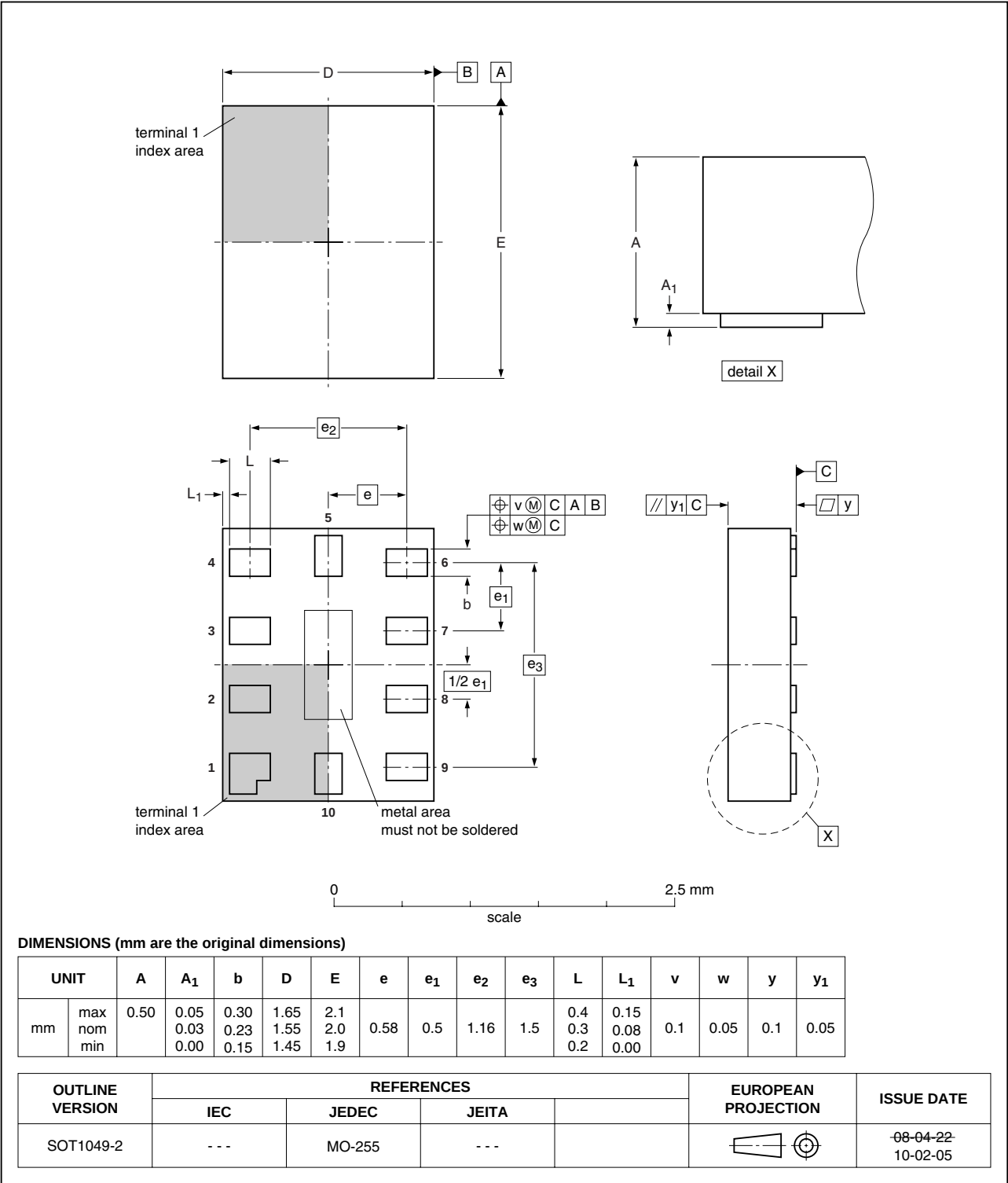


Fig 31. Package outline SOT1049-2 (XQFN10U)

HVSON10: plastic thermal enhanced very thin small outline package; no leads;
 10 terminals; body 3 x 3 x 0.85 mm

SOT650-1

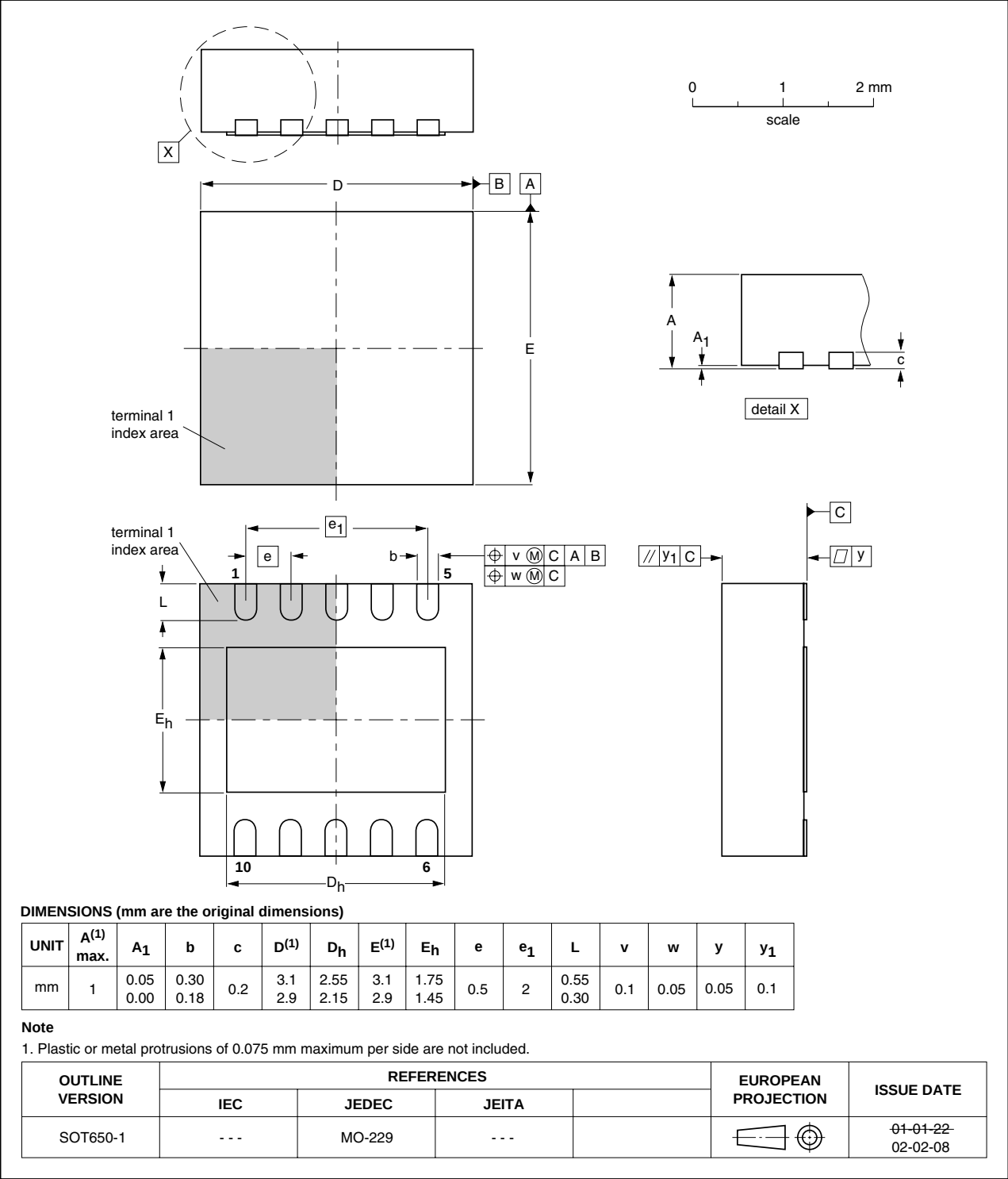


Fig 32. Package outline SOT650-1 (HVSON10)

14. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
PDA	Personal Digital Assistant

15. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L4684_4	20100324	Product data sheet	-	NX3L4684_3
NX3L4684_3	20100209	Product data sheet	-	NX3L4684_2
Modifications:	• Table 8 : ON resistance (flatness) for pins nY0 and nY1 changed at $V_{CC} = 4.3$ V.			
NX3L4684_2	20090401	Product data sheet	-	NX3L4684_1
NX3L4684_1	20081127	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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Date of release: 24 March 2010

Document identifier: NX3L4684_4